# International Rectifier

#### **AUTOMOTIVE GRADE**

# **AUIRLL014N**

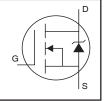
#### **Features**

- Advanced Planar Technology
- Low On-Resistance
- Dynamic dv/dt Rating
- 150°C Operating Temperature
- Fast Switching
- Fully Avalanche Rated
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified\*

#### **Description**

Specifically designed for Automotive applications, this cellular design of HEXFET® Power MOSFETs utilizes the latest processing techniques to achieve low onresistance per silicon area. This benefit combined with the fast switching speed and ruggedized device design that HEXFET power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in Automotive and a wide variety of other applications.

## HEXFET® Power MOSFET



V <sub>(BR)DSS</sub>	55V
R <sub>DS(on)</sub> max.	<b>0.14</b> Ω
I <sub>D</sub>	2.0A



G	D	S
Gate	Drain	Source

#### **Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature  $(T_A)$  is 25°C, unless otherwise specified.

	Parameter	Max.	Units
I <sub>D</sub> @ T <sub>A</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V ®	2.8	
I <sub>D</sub> @ T <sub>A</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>⑤</sup>	2.0	
I <sub>D</sub> @ T <sub>A</sub> = 70°C	Continuous Drain Current, V <sub>GS</sub> @ 10V ⑤	1.6	Α
I <sub>DM</sub>	Pulsed Drain Current ①	16	1
P <sub>D</sub> @T <sub>A</sub> = 25°C	Power Dissipation (PCB Mount) ®	2.1	w
P <sub>D</sub> @T <sub>A</sub> = 25°C	Power Dissipation (PCB Mount) <sup>⑤</sup>	1.0	7 VV
	Linear Derating Factor (PCB Mount) <sup>⑤</sup>	8.3	mW/°C
$V_{GS}$	Gate-to-Source Voltage	± 16	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Thermally Limited) ②	32	mJ
I <sub>AR</sub>	Avalanche Current ①	2.0	Α
E <sub>AR</sub>	Repetitive Avalanche Energy ①⑤	0.1	mJ
TJ	Operating Junction and	-55 to + 150	°C
T <sub>STG</sub>	Storage Temperature Range		

#### **Thermal Resistance**

	Parameter	Тур.	Max.	Units
$R_{\theta JA}$	Junction-to-Ambient (PCB mount, steady state) <sup>⑤</sup>	90	120	°C/W
$R_{\theta JA}$	Junction-to-Ambient (PCB mount, steady state) ©	50	60	

HEXFET® is a registered trademark of International Rectifier.

<sup>\*</sup>Qualification standards can be found at http://www.irf.com/

## Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	55		—	V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.015	—	V/°C	Reference to 25°C, I <sub>D</sub> = 1mA
				0.14		V <sub>GS</sub> = 10V, I <sub>D</sub> = 2.0A ④
R <sub>DS(on)</sub>	Static Drain-to-Source On-Resistance			0.20	Ω	V <sub>GS</sub> = 5.0V, I <sub>D</sub> = 1.2A ④
				0.28		V <sub>GS</sub> = 4.0V, I <sub>D</sub> = 1.0A ④
$V_{GS(th)}$	Gate Threshold Voltage	1.0		2.0	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
gfs	Forward Transconductance	2.3			S	$V_{DS} = 25V, I_D = 1.0A$
I <sub>DSS</sub>	Drain-to-Source Leakage Current			25	μΑ	$V_{DS} = 55V, V_{GS} = 0V$
				250		$V_{DS} = 44V, V_{GS} = 0V, T_{J} = 150^{\circ}C$
I <sub>GSS</sub>	Gate-to-Source Forward Leakage			100	nA	V <sub>GS</sub> = 16V
	Gate-to-Source Reverse Leakage			-100		V <sub>GS</sub> = -16V

## Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

•		•		•		• • •
	Parameter	Min.	Тур.	Max.	Units	Conditions
$Q_g$	Total Gate Charge		9.5	14		$I_D = 2.0A$
$Q_{gs}$	Gate-to-Source Charge		1.1	1.7	nC	$V_{DS} = 44V$
$Q_{gd}$	Gate-to-Drain ("Miller") Charge		3.0	4.4		V <sub>GS</sub> = 10V, See Fig. 6 and 9 ④
t <sub>d(on)</sub>	Turn-On Delay Time		5.1			$V_{DD} = 28V$
t <sub>r</sub>	Rise Time		4.9		ns	$I_D = 2.0A$
$t_{d(off)}$	Turn-Off Delay Time		14			$R_G = 6.0 \Omega$
t <sub>f</sub>	Fall Time		2.9			$R_D = 14\Omega$ , See Fig. 10 $\square$ $\oplus$
C <sub>iss</sub>	Input Capacitance		230			$V_{GS} = 0V$
C <sub>oss</sub>	Output Capacitance		66		pF	$V_{DS} = 25V$
C <sub>rss</sub>	Reverse Transfer Capacitance		30			f = 1.0MHz, See Fig. 5

#### **Diode Characteristics**

	Parameter	Min.	Тур.	Max.	Units	Conditions
I <sub>S</sub>	Continuous Source Current			1.3		MOSFET symbol p
	(Body Diode)				Α	showing the
I <sub>SM</sub>	Pulsed Source Current			16		integral reverse G
	(Body Diode) ①					p-n junction diode.
$V_{SD}$	Diode Forward Voltage			1.0	V	$T_J = 25^{\circ}C$ , $I_S = 2.0A$ , $V_{GS} = 0V$ ④
t <sub>rr</sub>	Reverse Recovery Time		41	61	ns	T <sub>J</sub> = 25°C, I <sub>F</sub> = 2.0A
Q <sub>rr</sub>	Reverse Recovery Charge		73	110	nC	di/dt = 100A/µs ⊕
t <sub>on</sub>	Forward Turn-On Time	Intrinsio	turn-or	time is	negligible	(turn-on is dominated by LS+LD)

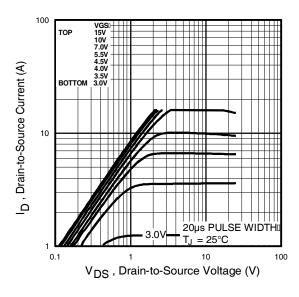
#### Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature. ( See fig. 11)
- ②  $V_{DD}$  = 25V, starting  $T_J$  = 25°C, L = 4.0mH  $R_G$  = 25 $\Omega$ ,  $I_{AS}$  = 4.0A. (See Figure 12)
- $\label{eq:loss} \begin{tabular}{ll} \begin$
- When mounted on FR-4 board using minimum recommended footprint.
- When mounted on 1 inch square copper board, for comparison with other SMD devices.

## Qualification Information<sup>†</sup>

		Automotive (per AEC-Q101)				
Qualification Level		Comments: This part number(s) passed Automot qualification. IR's Industrial and Consumer qualificat level is granted by extension of the higher Automot level.				
Moisture Sensitivity	Level	SOT-223 MSL1				
	Machine Model		Class M1A (+/- 50V) <sup>†††</sup>			
		AEC-Q101-002				
FOD	Human Body Model	Class H0 (+/- 250V) <sup>†††</sup>				
ESD		AEC-Q101-001				
	Charged Device Model	Class C5 (+/- 1125V) <sup>†††</sup>				
		AEC-Q101-005				
RoHS Compliant	!	Yes				

- † Qualification standards can be found at International Rectifier's web site: http://www.irf.com/
- †† Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.
- ††† Highest passsing voltage.



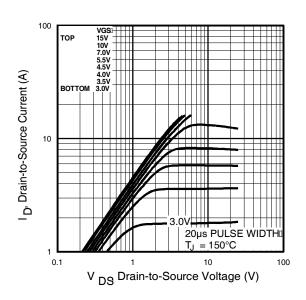
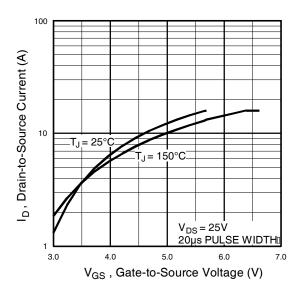


Fig 1. Typical Output Characteristics,

Fig 2. Typical Output Characteristics,



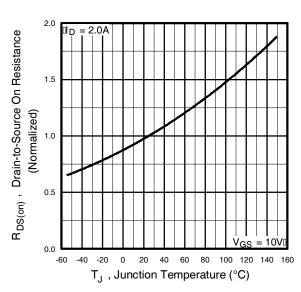
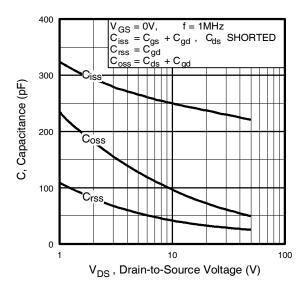
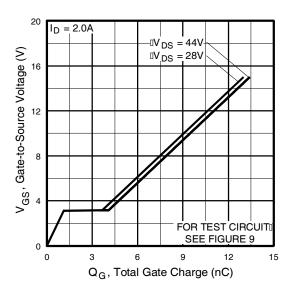


Fig 3. Typical Transfer Characteristics

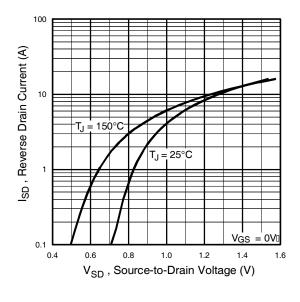
**Fig 4.** Normalized On-Resistance Vs. Temperature





**Fig 5.** Typical Capacitance Vs. Drain-to-Source Voltage

**Fig 6.** Typical Gate Charge Vs. Gate-to-Source Voltage



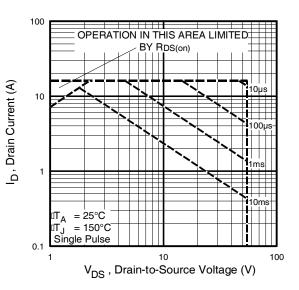


Fig 7. Typical Source-Drain Diode Forward Voltage

Fig 8. Maximum Safe Operating Area

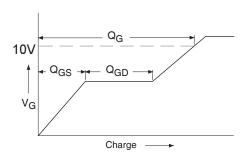
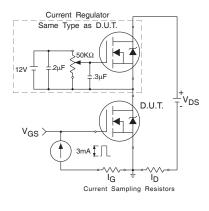


Fig 9a. Basic Gate Charge Waveform

Fig 10a. Switching Time Test Circuit



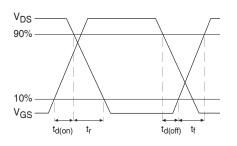


Fig 9b. Gate Charge Test Circuit

Fig 10b. Switching Time Waveforms

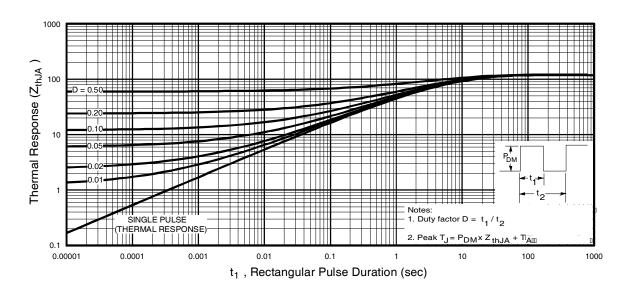


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

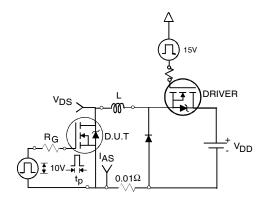


Fig 12a. Unclamped Inductive Test Circuit

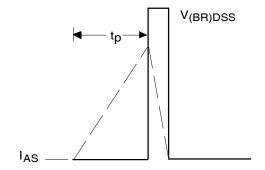


Fig 12b. Unclamped Inductive Waveforms

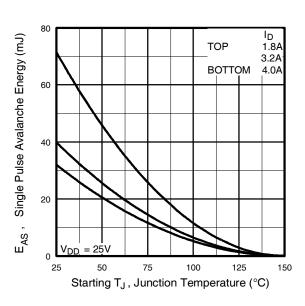
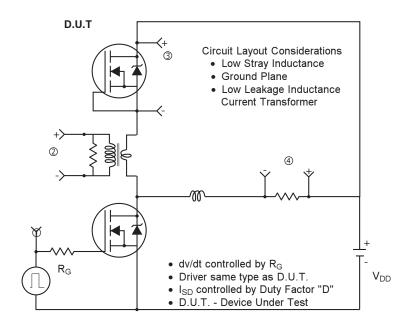
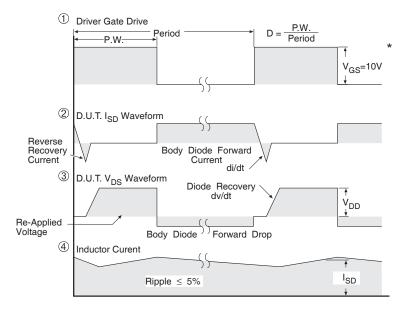


Fig 12c. Maximum Avalanche Energy Vs. Drain Current

## Peak Diode Recovery dv/dt Test Circuit





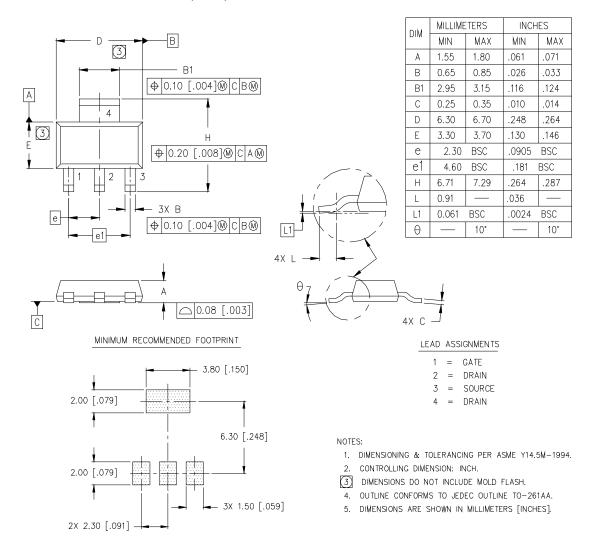
<sup>\*</sup>  $V_{GS}$  = 5V for Logic Level Devices

Fig 13. For N-Channel HEXFETS

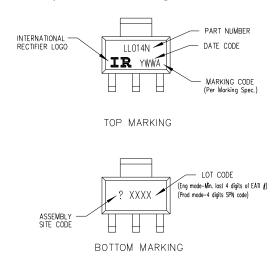
## **AUIRLL014N**

## SOT-223 (TO-261AA) Package Outline

Dimensions are shown in milimeters (inches)



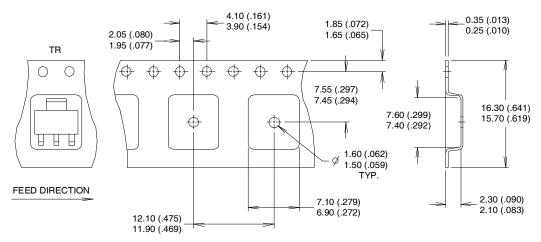
## SOT-223 (TO-261AA) Part Marking Information



Note: For the most current drawing please refer to IR website at <a href="http://www.irf.com/package/">http://www.irf.com/package/</a> www.irf.com

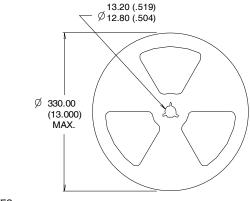
## SOT-223 (TO-261AA) Tape & Reel Information

Dimensions are shown in milimeters (inches)



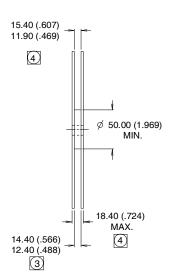
#### NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. OUTLINE CONFORMS TO EIA-481 & EIA-541.
- 3. EACH Ø330.00 (13.00) REEL CONTAINS 2,500 DEVICES.





- 1. OUTLINE COMFORMS TO EIA-418-1.
- 2. CONTROLLING DIMENSION: MILLIMETER..
- DIMENSION MEASURED @ HUB.
- INCLUDES FLANGE DISTORTION @ OUTER EDGE.



# **Ordering Information**

Base part	Package Type	Standard Pack	Complete Part Number	
		Form	Quantity	
AUIRLL014N	SOT-223	Tube	95	AUIRLL014N
		Tape and Reel	2500	AUIRLL014NTR

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